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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/053,424	11/02/2001	Johan Agus Darmawan	020303-007200US 4303	
20350	7590 12/04/2002			
TOWNSEND AND TOWNSEND AND CREW, LLP TWO EMBARCADERO CENTER EIGHTH FLOOR			EXAMINER	
			TRAN, TAN N	
SAN FRANCISCO, CA 94111-3834			ART UNIT	PAPER NUMBER
			2826	
			DATE MAILED: 12/04/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

ξ,		Application No.	Applicant(s)			
Office Action Summary		10/053,424	DARMAWAN, JOHAN AGUS			
		Examiner	Art Unit			
The MAN INC DATE AND		TAN N TRAN	2826			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply secified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).						
Status						
1)⊠	Responsive to communication(s) filed on <u>02 N</u>					
2a) 🗌	-	s action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims						
4)⊠ Claim(s) <u>1-23</u> is/are pending in the application.						
4a) Of the above claim(s) <u>1-14</u> is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>15-23</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement. Application Papers						
9)☐ The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) □ accepted or b) □ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12)⊠ The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) The translation of the foreign language provisional application has been received.						
15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
2) Notice (3) Informa	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) ation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal Par	PTO-413) Paper No(s) tent Application (PTO-152)			
Patent and Trad O-326 (Rev.		on Summary	Part of Paper No. 7			

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DETAILED ACTION

1. Applicant's election of Group I, claims 15-23 in Paper No. 6 is acknowledged.

Information Disclosure Statement

2. If applicant is aware of any relevant prior art, he/she requested to cite it on form PTO-1449 in accordance with the guidelines set forth in M.P.E.P. 609.

Oath/Declaration

3. The oath or declaration is defective. A new oath or declaration in compliance with 37 CFR 1.67(a) identifying this application by application number and filing date is required. See MPEP §§ 602.01 and 602.02.

The oath or declaration is defective because:

It does not identify the mailing or post office address of each inventor. A mailing or post office address is an address at which an inventor customarily receives his or her mail and may be either a home or business address. The mailing or post office address should include the ZIP Code designation. The mailing or post office address may be provided in an application data sheet or a supplemental oath or declaration. See 37 CFR 1.63(c) and 37 CFR 1.76.

Claim Rejections - 35 USC § 112

4. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

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Claims 15-23 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 15, line 3, "the silicon oxide layer" lacks of antecedent basis.

In claim 15, lines 2,3, "a silicon layer supported by the substrate" is unclear as to whether it is being referred to a silicon oxide layer supported by the substrate.

Claim Rejections - 35 USC § 102

5. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

Claims 15-23 rejected under 35 U.S.C. 102(e) as being anticipated by Lin (6,483,147).

With regard to claim 15, Lin discloses a semiconductor device comprising a semiconductor body including a silicon substrate 12, a silicon oxide layer 34 formed on the substrate 12 for removing heat from the MOSFET 42, and a silicon device layer 32 overlying the silicon oxide layer 34, a metal layer 38(or 50,52) in the portion of the substrate 12, (note lines 28-30, column 5, fig.8 of Lin) a semiconductor component MOSFET 42 formed in the silicon device layer 32 overlying the conductive plug 38, that is formed in a portion of the substrate 12. (Note figs. 7 and 8 of Lin).

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With regard to claim 16, Lin discloses the silicon oxide layer 34 overlying the portion of

the substrate 12 is removed, the metal layer 38(or 50,52) abutting the silicon layer 32. (Note lines

28-30, column 5, fig.8 of Lin).

With regard to claim 20, Lin discloses the sides of the metal layer 38(or 50, 52) abuts the

silicon oxide layer 34. (Note figs.7,8 of Lin).

With regard to claims 17-19,21-23, Lin discloses the metal layer 52 comprises gold or

copper or aluminum and a refractory metal 50 such as titanium nitride. (Note lines 64-67 in

column 3 and lines 1-9, column 4, figs. 7,8 of Lin).

With regard to claim 20, Lin discloses the metal layer 502 abuts the silicon oxide layer-

34. (Note fig.8 of Lin).

Conclusion

6. Any inquiry concerning this communication or earlier communication from the examiner

should be directed to Tan Tran whose telephone number is (703) 305-3362. The examiner can

normally be reached on M-F 8:30AM-5PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the

organization where this application or proceeding is assigned are (703) 308-7722 for regular

communications and (703) 308-7724 for after final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is (703) 308-0956.

TT

Nov 2002

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